BLC9G20LS-160PV

Power LDMOS transistor

AMPLEON

Rev. 1 — 2 June 2016

Product data sheet

1. Product profile

1.1 General description

160 W LDMOS power transistor with enhanced video bandwidth for base station applications at frequencies from 1805 MHz to 2000 MHz.

Table 1. Typical performance

Typical RF performance at T_{case} = 25 $^{\circ}$ C in a common source class-AB demo test circuit.

Test signal	f	I_{Dq}	V _{DS}	P _{L(AV)}	G_p	η_D	ACPR _{5M}
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dBc)
1-carrier W-CDMA	1805 to 1880	860	28	38	20	38	-35 <u>[1]</u>

^[1] Test signal: 3GPP test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability on CCDF per carrier; 5 MHz carrier spacing.

1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low thermal resistance providing excellent thermal stability
- Decoupling leads to enable enhanced video bandwidth performance (70 MHz typical)
- Designed for broadband operation (1805 MHz to 2000 MHz)
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent pre-distortability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

RF power amplifiers for base stations and multi carrier applications in the 1805 MHz to 2000 MHz frequency range

2. Pinning information

Table 2. Pinning

Pin	Description	Sii	implified outline	Graphic symbol
1	drain1			
2	drain2	5		1, 5
3	gate1			3_
4	gate2		7	7
5	video decoupling			47
6	video decoupling		3 4	2, 6
7	source	[1]		aaa-007731

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Packag	ackage		
	Name	Description	Version	
BLC9G20LS-160PV	-	air cavity plastic earless flanged package; 6 leads	SOT1275-1	

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V_{GS}	gate-source voltage		-6	+13	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	225	°C

^[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

Symb	Parameter	Conditions	Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	T _{case} = 80 °C; P _L = 38 W	0.310	K/W

6. Characteristics

Table 6. DC characteristics

 T_i = 25 °C per section, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.7 \text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 72 mA	1.5	1.9	2.3	V
V_{GSq}	gate-source quiescent voltage	V _{DS} = 28 V; I _D = 430 mA	1.7	2.1	2.5	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 32 V	-	-	1.4	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	14	-	A
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	140	nA
g _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 72 mA	-	0.64	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 2.5 A$	-	0.18	-	Ω

Table 7. RF characteristics

Test signal: 1-carrier W-CDMA; 3GPP test model 1 with 64 DPCH; PAR = 7.2 dB at 0.01 % probability on the CCDF; RF performance at V_{DS} = 28 V; I_{Dq} = 860 mA (whole device); T_{case} = 25 °C; unless otherwise specified; in a water cooled class-AB test circuit at frequencies from 1805 MHz to 1880 MHz.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	P _{L(AV)} = 38 W	18.6	19.8	-	dB
η_{D}	drain efficiency	P _{L(AV)} = 38 W	29.5	34.5	-	%
RLin	input return loss	P _{L(AV)} = 38 W	-	-10	-4	dB
ACPR _{5M}	adjacent channel power ratio (5 MHz)	P _{L(AV)} = 38 W	-	-30	-25	dBc

7. Test information

7.1 Ruggedness in class-AB operation

The BLC9G20LS-160PV is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 28 V; I_{Dq} = 860 mA; P_L = 120 W (CW); f = 1805 MHz.

7.2 Impedance information

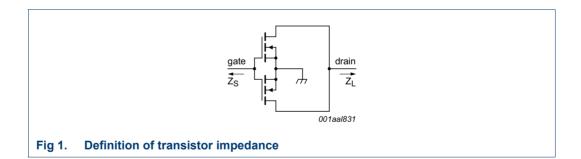
Table 8. Typical impedance

Measured load-pull data; I_{Dq} = 860 mA; V_{DS} = 28 V. Typical values unless otherwise specified.

f	Z _S [1]	Z _L [1]	P _L [1]	η _D [2]	G _p [2]
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)
Maximum power load					
1805	1.0 – j3.7	1.2 – j3.6	189	60.5	16.3
1843	1.4 – j4.3	1.2 – j3.6	189	61.4	16.4
1880	1.5 – j5.0	0.9 – j3.7	189	55.3	16.0
Maximum dra	in efficiency load				
1805	1.0 – j3.7	2.0 - j2.5	127	68.9	18.4
1843	1.4 – j4.3	1.8 – j2.3	120	68.8	18.5
1880	1.5 – j5.0	1.7 – j2.5	126	67.4	18.6

^[1] Z_S and Z_L defined in Figure 1.

^[2] at 3 dB gain compression.



7.3 VBW in class-AB operation

The BLC9G20LS-160PV shows 70 MHz (typical) video bandwidth in a class-AB test circuit in 1842.5 MHz band at V_{DS} = 28 V and I_{Dq} = 860 mA.

7.4 Test circuit

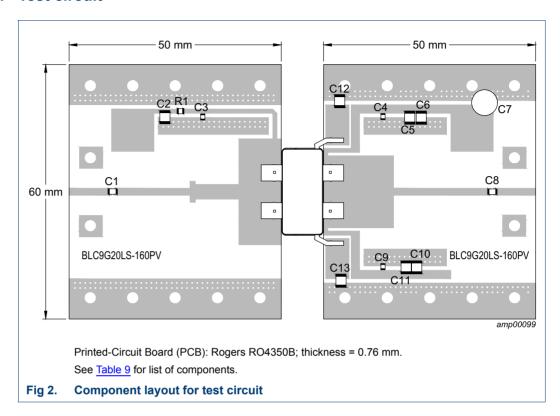
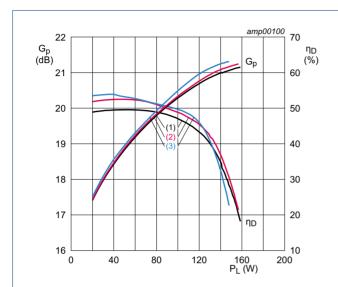


Table 9. List of components For test circuit, see Figure 2.

Component	Description	Value	Remarks
C1, C3, C4, C8, C9	multilayer ceramic chip capacitor	36 pF	ATC600F
C2, C5, C6, C10, C11, C12, C13	multilayer ceramic chip capacitor	4.7 μF, 72 V	Murata
C7	electrolytic capacitor	2200 μF, 50 V	
R1	chip resistor	5.1 Ω	SMD 0805

7.5 Graphical data

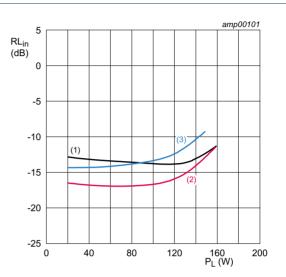
7.5.1 CW



 V_{DS} = 28 V; I_{Dq} = 860 mA (whole device); V_{GS} = 2.13 V.

- (1) f = 1805 MHz
- (2) f = 1842.5 MHz
- (3) f = 1880 MHz

Fig 3. Power gain and drain efficiency as function of output power; typical values

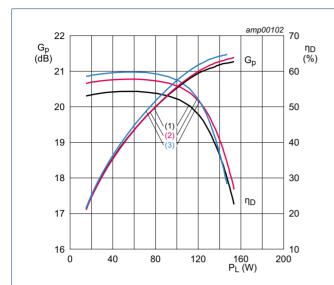


 V_{DS} = 28 V; I_{Dq} = 860 mA (whole device); V_{GS} = 2.13 V.

- (1) f = 1805 MHz
- (2) f = 1842.5 MHz
- (3) f = 1880 MHz

Fig 4. Input return loss as a function of output power; typical values

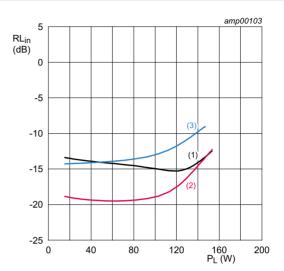
7.5.2 CW pulsed



 V_{DS} = 28 V; I_{Dq} = 860 mA (whole device); V_{GS} = 2.13 V.

- (1) f = 1805 MHz
- (2) f = 1842.5 MHz
- (3) f = 1880 MHz

Fig 5. Power gain and drain efficiency as function of output power; typical values

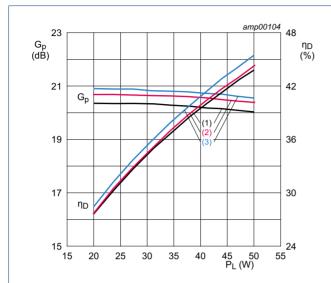


 V_{DS} = 28 V; I_{Dq} = 860 mA (whole device); V_{GS} = 2.13 V.

- (1) f = 1805 MHz
- (2) f = 1842.5 MHz
- (3) f = 1880 MHz

Fig 6. Input return loss as a function of output power; typical values

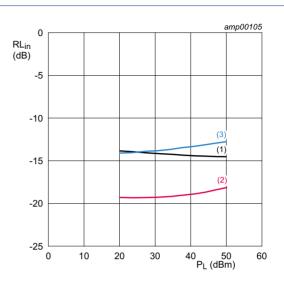
7.5.3 1-Carrier W-CDMA



 V_{DS} = 28 V; I_{Dq} = 860 mA (whole device); V_{GS} = 2.13 V.

- (1) f = 1805 MHz
- (2) f = 1842.5 MHz
- (3) f = 1880 MHz

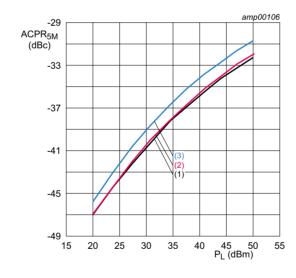
Fig 7. Power gain and drain efficiency as function of output power; typical values



 V_{DS} = 28 V; I_{Dq} = 860 mA (whole device); V_{GS} = 2.13 V.

- (1) f = 1805 MHz
- (2) f = 1842.5 MHz
- (3) f = 1880 MHz

Fig 8. Input return loss as a function of output power; typical values

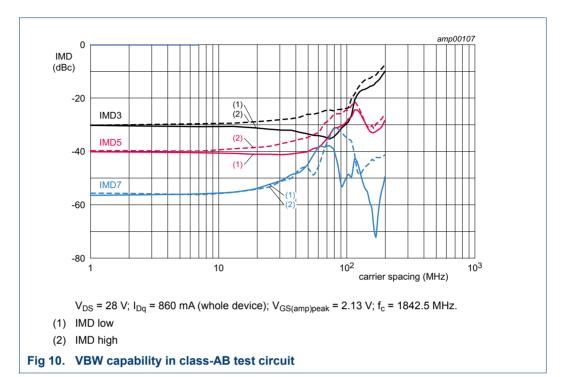


 V_{DS} = 28 V; I_{Dq} = 860 mA (whole device); V_{GS} = 2.13 V.

- (1) f = 1805 MHz
- (2) f = 1842.5 MHz
- (3) f = 1880 MHz

Fig 9. Adjacent channel power ratio (5 MHz) as a function of output power; typical values

7.5.4 2-Tone VBW



8. Package outline

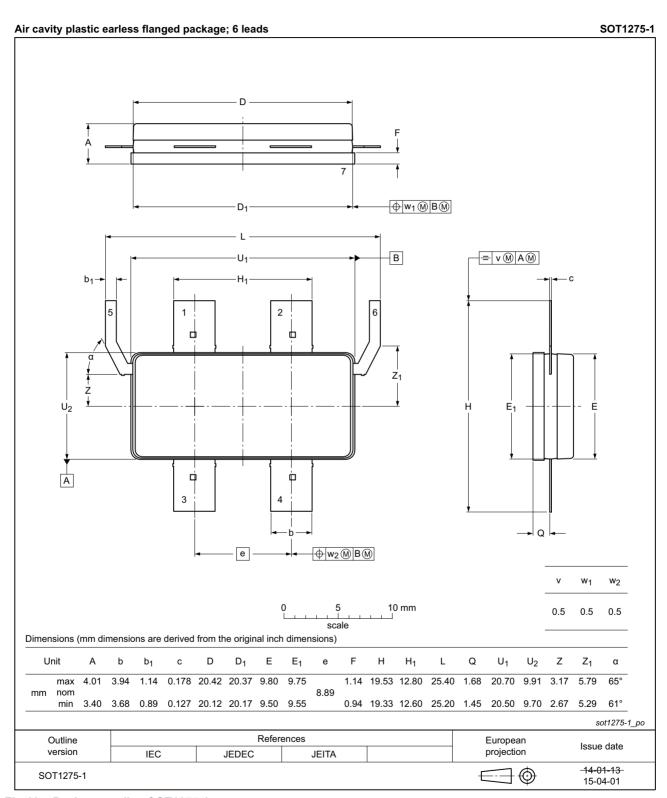


Fig 11. Package outline SOT1275-1

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

10. Abbreviations

Table 10. Abbreviations

Acronym	Description	
3GPP	3rd Generation Partnership Project	
CCDF	Complementary Cumulative Distribution Function	
CW	Continuous wave	
DPCH	Dedicated Physical CHannel	
ESD	ElectroStatic Discharge	
LDMOS	Laterally Diffused Metal Oxide Semiconductor	
MTF	Median Time to Failure	
PAR	Peak-to-Average Ratio	
SMD	Surface Mounted Device	
VBW	Video Bandwidth	
VSWR	Voltage Standing Wave Ratio	
W-CDMA	Wideband Code Division Multiple Access	

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLC9G20LS-160PV v.1	20160602	Product data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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